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HALOGEN

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Vishay Semiconductors

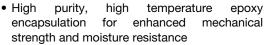
High Performance Schottky Rectifier, 2 x 10 A

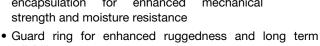


PRIMARY CHARACTERISTICS								
I _{F(AV)} 2 x 10 A								
V_{R}	150 V							
V _F at I _F	0.66 V							
I _{RM} max.	5 mA at 125 °C							
TJ	175 °C							
E _{AS}	2.45 mJ							
Package	3L TO-220AB							
Circuit configuration	Common cathode							

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation





- reliability
- Designed and qualified according to JEDEC®-JESD 47
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION

The center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	20	Α					
V _{RRM}		150	V					
I _{FSM}	t _p = 5 μs sine	1030	Α					
V_{F}	10 A _{pk} , T _J = 125 °C (per leg)	0.66	V					
T _J	Range	-55 to +175	°C					

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-20CTQ150-M3 UNITS								
Maximum DC reverse voltage	V _R	150	V					
Maximum working peak reverse voltage	V _{RWM}	130	v					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST COND	VALUES	UNITS			
Maximum average forward pe			EO 0/ duty ovelopt T 154 °C rectongular varietares		10	А		
current, see fig. 5	per device	I _{F(AV)}	50 % duty cycle at T _C = 154 °C, rectangular waveform		20			
Maximum peak one cycle no	Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load	1030	А		
surge current per leg, see fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	180			
Non-repetitive avalanche energy per leg		E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 0.7 \text{A}, L = 10 \text{mH}$		2.45	mJ		
Repetitive avalanche current per leg		I _{AR}		Current decaying linearly to zero in 1 µs Frequency limited by T _J maximum V _A = 1.5 x V _R typical		Α		



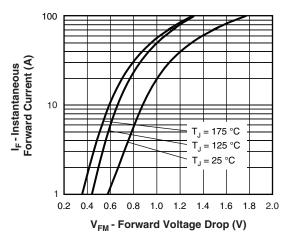
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS			
		10 A	T _{.1} = 25 °C	0.80	0.88			
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	20 A	1j=25 C	0.90	1.0	V		
See fig. 1	VFM (1)	10 A	T _{.1} = 125 °C	0.63	0.66			
		20 A	1j = 125 C	0.73	0.77			
Maximum reverse leakage current per leg	I _{RM}	T _J = 25 °C	V _R = Rated V _R	3.0	25	μΑ		
See fig. 2		T _J = 125 °C	VR = nateu VR	2.7	5.0	mA		
Typical junction capacitance per leg C _T		$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		-	280	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body			8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R	-	10 000	V/µs			

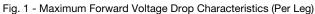
Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		- 55 to 175	°C			
Maximum thermal resistance, junction to case per leg Maximum thermal resistance, junction to case per package		D	DC anaration	2.0				
		R_{thJC}	DC operation	1.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50				
Annyovimata waisht				2	g			
Approximate weight				0.07	OZ.			
Maunting torque	minimum			6 (5)	kgf · cm			
Mounting torque —	maximum			12 (10)	(lbf · in)			
Marking device			Case style 3L TO-220AB	20CTQ150				







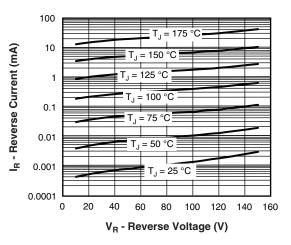


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

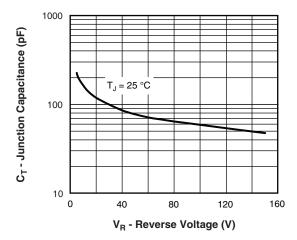


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

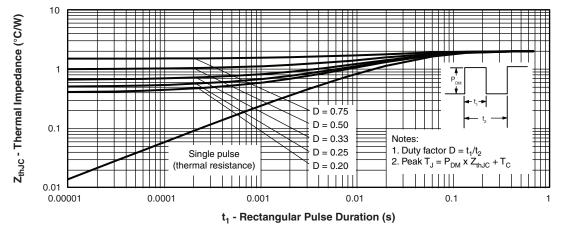


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)



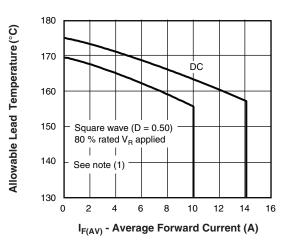


Fig. 5 - Maximum Average Forward Current vs.
Allowable Lead Temperature

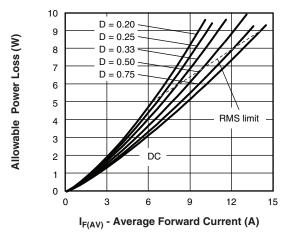


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

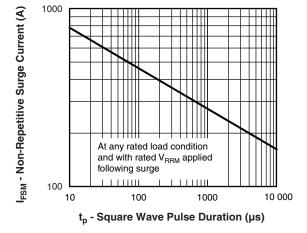


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

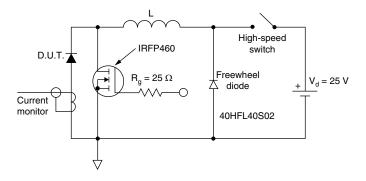


Fig. 8 - Unclamped Inductive Test Circuit

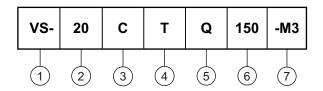
Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (20 = 20 A)

3 - Circuit configuration:

C = Common cathode

4 - Package:

T = TO-220

5 - Schottky "Q" series

6 - Voltage ratings (150 = 150 A)

7 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

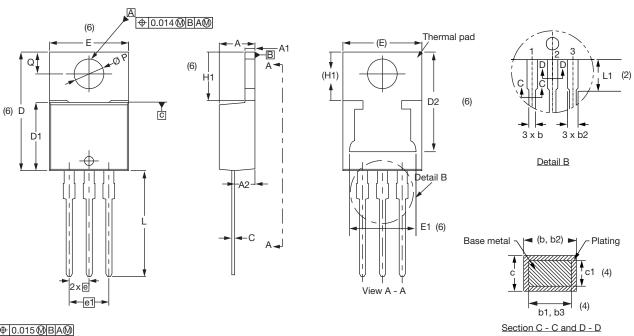
ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-20CTQ150-M3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?96154</u>							
Part marking information	www.vishay.com/doc?95028						

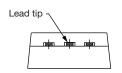


3L TO-220AB

DIMENSIONS in millimeters and inches



⊕ 0.015 **M** B A **M**



Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355		1		•			•	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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Vishay

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